

**2SJ191**

Ultrahigh-Speed Switching Applications

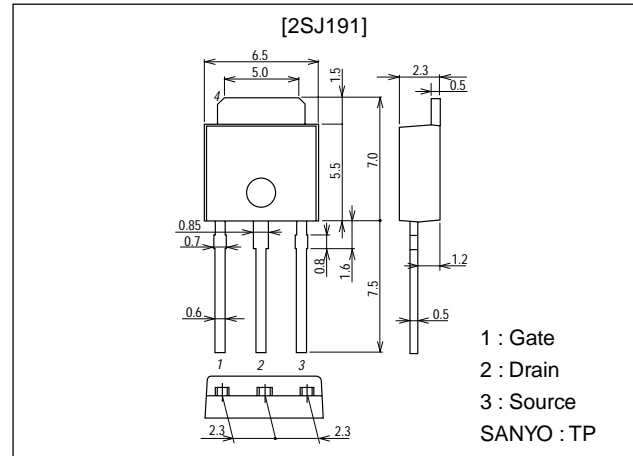
Features

- Low ON resistance.
- Ultrahigh-speed switching.
- Low-voltage drive.

Package Dimensions

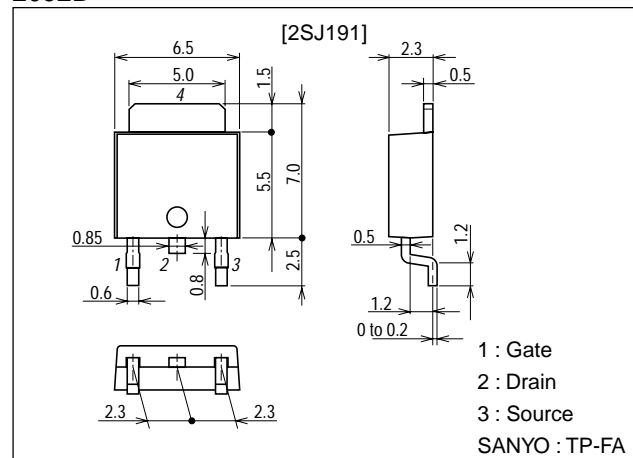
unit:mm

2083B



unit:mm

2092B



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Specifications

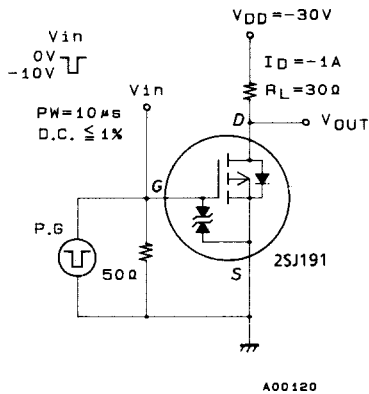
Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		-60	V
Gate-to-Source Voltage	V_{GSS}		±15	V
Drain Current (DC)	I_D		-2	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	-8	A
Allowable Power Dissipation	P_D	$T_c = 25^\circ C$	20	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

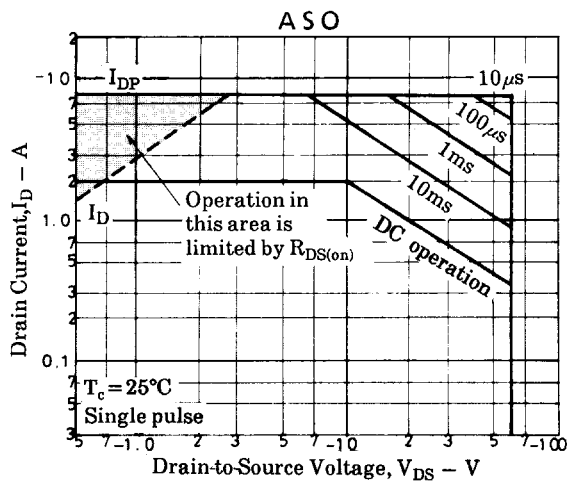
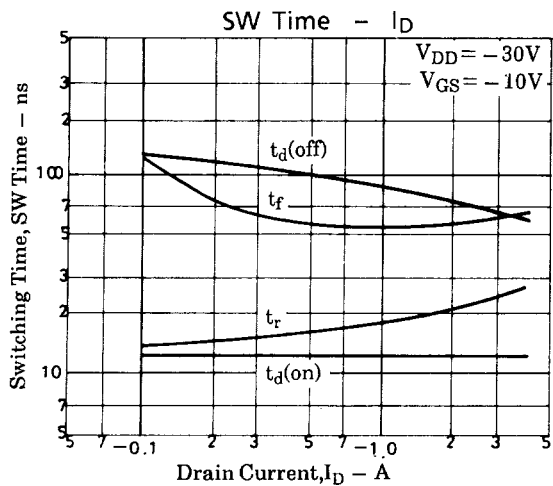
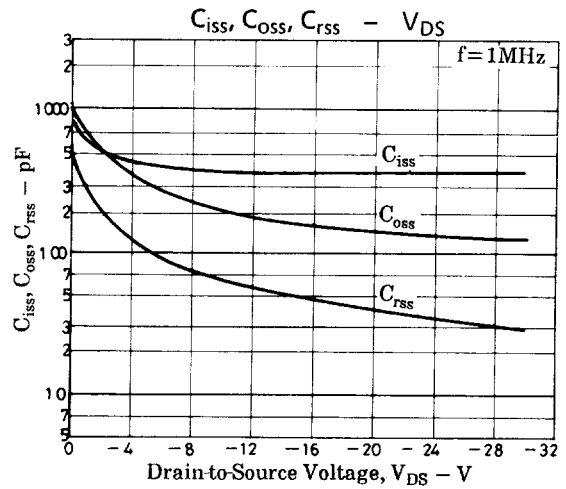
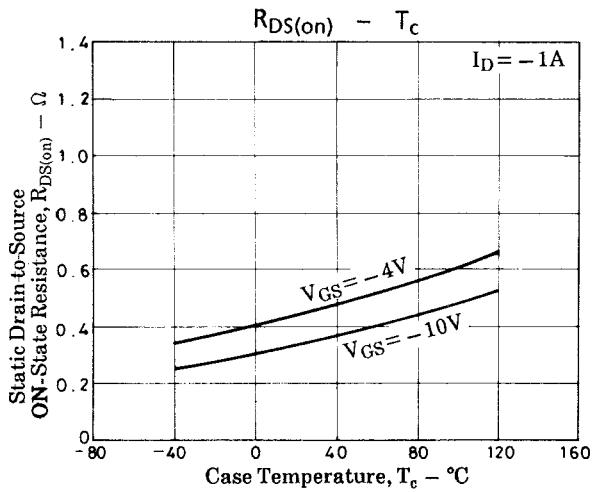
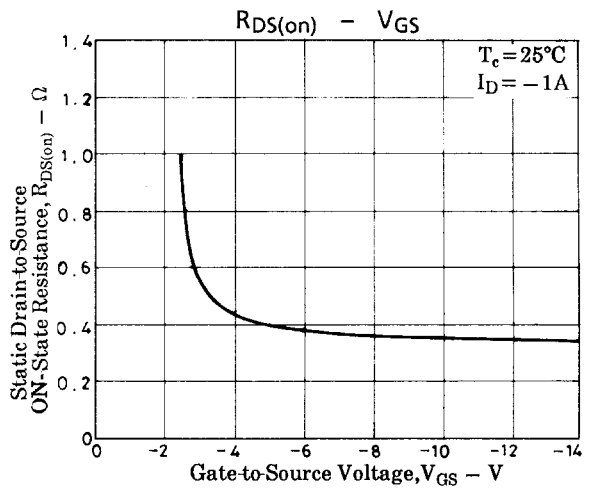
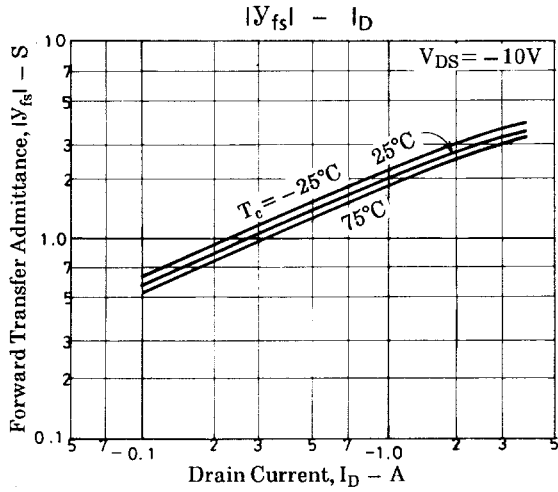
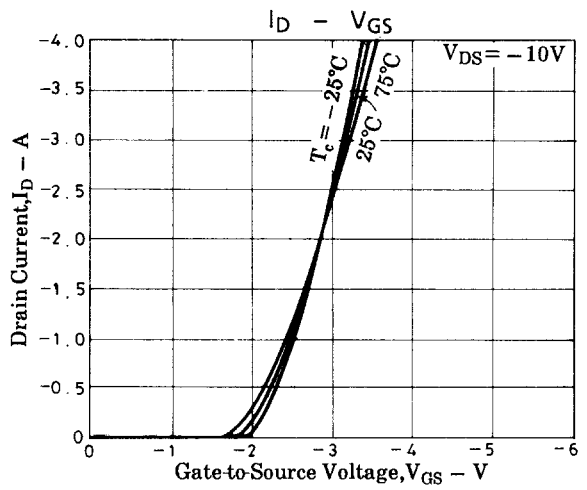
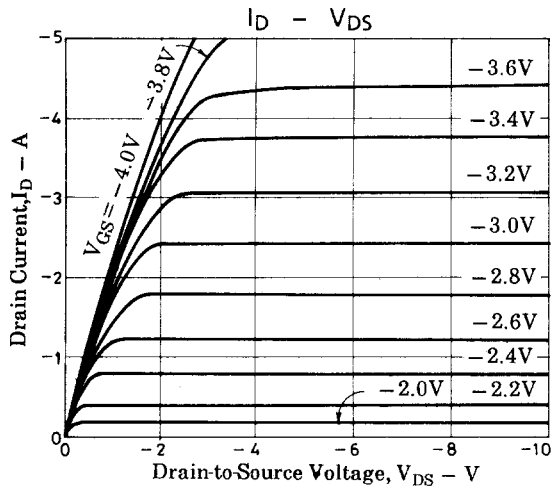
Electrical Characteristics at Ta = 25°C

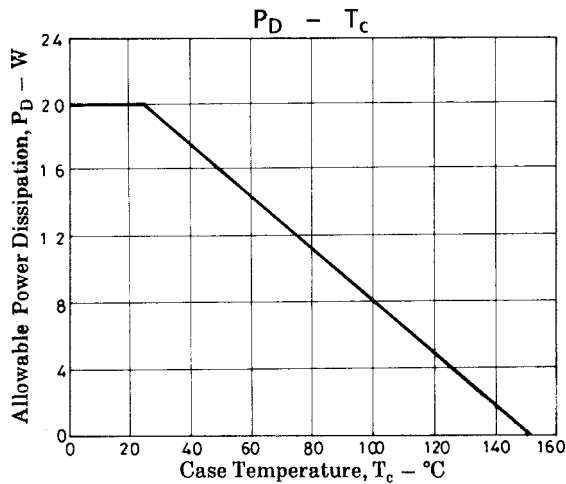
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = -1mA$, $V_{GS} = 0$	-60			V
Gate-to-Source Breakdown Voltage	$V_{(BR)GSS}$	$I_G = \pm 100\mu A$, $V_{DS} = 0$	±15			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -60V$, $V_{GS} = 0$			-100	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 12V$, $V_{DS} = 0$			±10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = -10V$, $I_D = -1mA$	-1.0		-2.0	V
Forward Transfer Admittance	yfs	$V_{DS} = -10V$, $I_D = -1A$	1.2	2		S
Static Drain-to-Source ON-State Resistance	$R_{DS(on)}$	$I_D = -1A$, $V_{GS} = -10V$		0.35	0.45	Ω
	$R_{DS(on)}$	$I_D = -1A$, $V_{GS} = -4V$		0.45	0.6	Ω
Input Capacitance	Ciss	$V_{DS} = -20V$, $f = 1MHz$		380		pF
Output Capacitance	Coss	$V_{DS} = -20V$, $f = 1MHz$		150		pF
Reverse Transfer Capacitance	Crss	$V_{DS} = -20V$, $f = 1MHz$		40		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit		12		ns
Rise Time	t_r	See specified Test Circuit		18		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit		85		ns
Fall Time	t_f	See specified Test Circuit		55		ns
Diode Forward Voltage	V_{SD}	$I_S = -2A$, $V_{GS} = 0$		-1.0	-1.5	V

Switching Time Test Circuit



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